

XMC4000

Microcontroller Series
for Industrial Applications

Hibernate

- ✓ Hibernate Mode Basics
- ✓ Hibernate Mode Implementations
- ✓ Control of External Voltage Regulator
- ✓ Getting Started
- ✓ Application Hints

Device Guide

V1.0 2013-04

Edition 2013-04

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Infineon Technologies AG
81726 Munich, Germany
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Page or Item	Subjects (major changes since previous revision)
V1.0, 2013.04	Release

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Hibernate Mode Basics

1 Hibernate Mode Basics

Hibernate Mode is one of the system power states of the XMC4000 device. The XMC4000 device implements Power Management control that aims at reduction of power consumption. The available Power Modes (also referred to as Power States) of the system, depicted in Figure 1., offer different features they may be utilized in an application specific manner, with the focus on different aspects, like current consumption, transition time between states, system topology, etc.

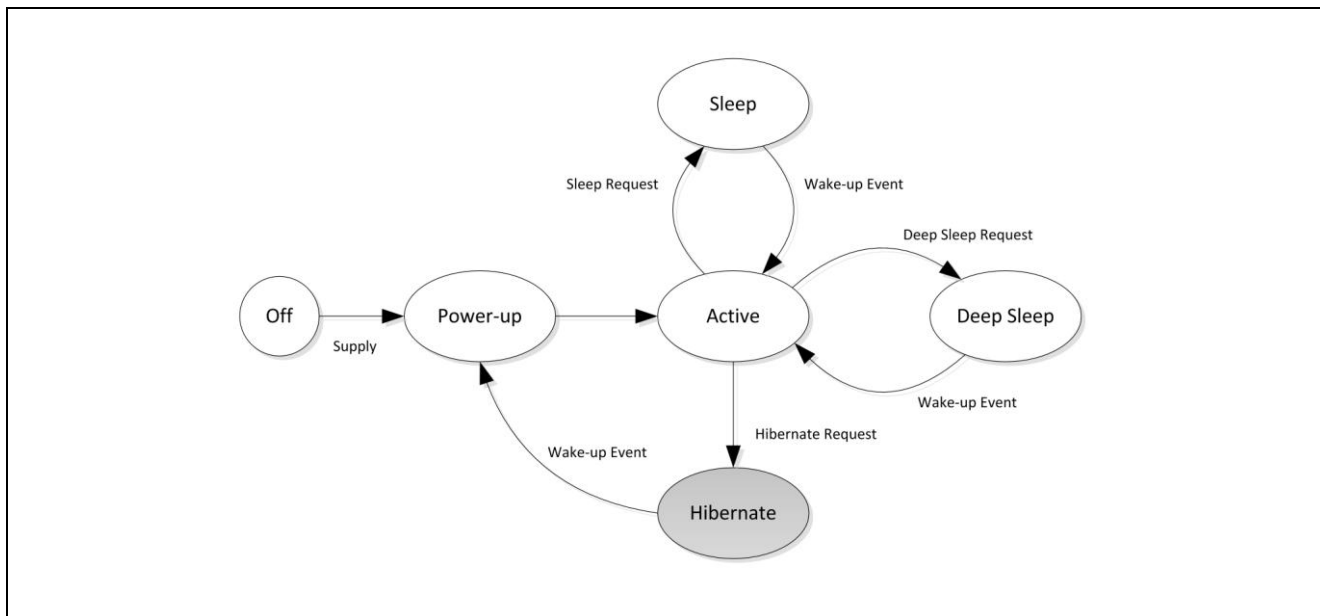


Figure 1 System Power States

The XMC family implements the following Power Modes:

- Active Mode - the normal operation state.
 - Entered automatically after system reset release
- Sleep Mode - clock of the CPU and selected peripherals is stopped.
 - Entered via WFI or WFE instruction of the CPU (for details please refer to Cortex-M4 documentation)
 - Wake-up on any valid interrupt/exception
- Deep Sleep Mode – similar to Sleep Mode, with an ability to power down additional peripherals
 - Entered via WFI or WFE instruction of the CPU (for details please refer to Cortex-M4 documentation)
 - Wake-up on any valid interrupt/exception
- Hibernate Mode – Power Supply to the chip or to the core (on some family XMC4000 family members) is switched off and only Hibernate Domain remain powered on

The Hibernate Mode is the power mode of the lowest power consumption, offering Real Time Clock keeping and preservation of a context specific data in a retention memory (for details on power consumption and timing figures please refer to Data Sheet). Transitions into and from the power states are controlled with user software and valid wake-up events respectively. The wake-up trigger events may be generated by different sources, like external signals or RTC events, configured by the user prior to entering a power saving state.

There are two implementations of the Hibernate Mode Control.

- Externally Controlled Hibernate Mode (ECHM) with an IO actively controlling External Voltage Regulator

- Internally Controlled Hibernate Mode (ICHM) with an internal signal actively controlling Embedded Voltage Regulator (EVR)

1.1 Externally Controlled Hibernate Use Cases

Generic application scenarios of Externally Controlled Hibernate Mode are illustrated in Figure 2. These use case scenarios enable the XMC4000 to act as a system Power Control Master. All system components supplied with VDDP are powered off and no current is drawn in the VDDP power domain. Upon a wake-up trigger complete VDDP power domain of the system on PCB will be brought into operation.

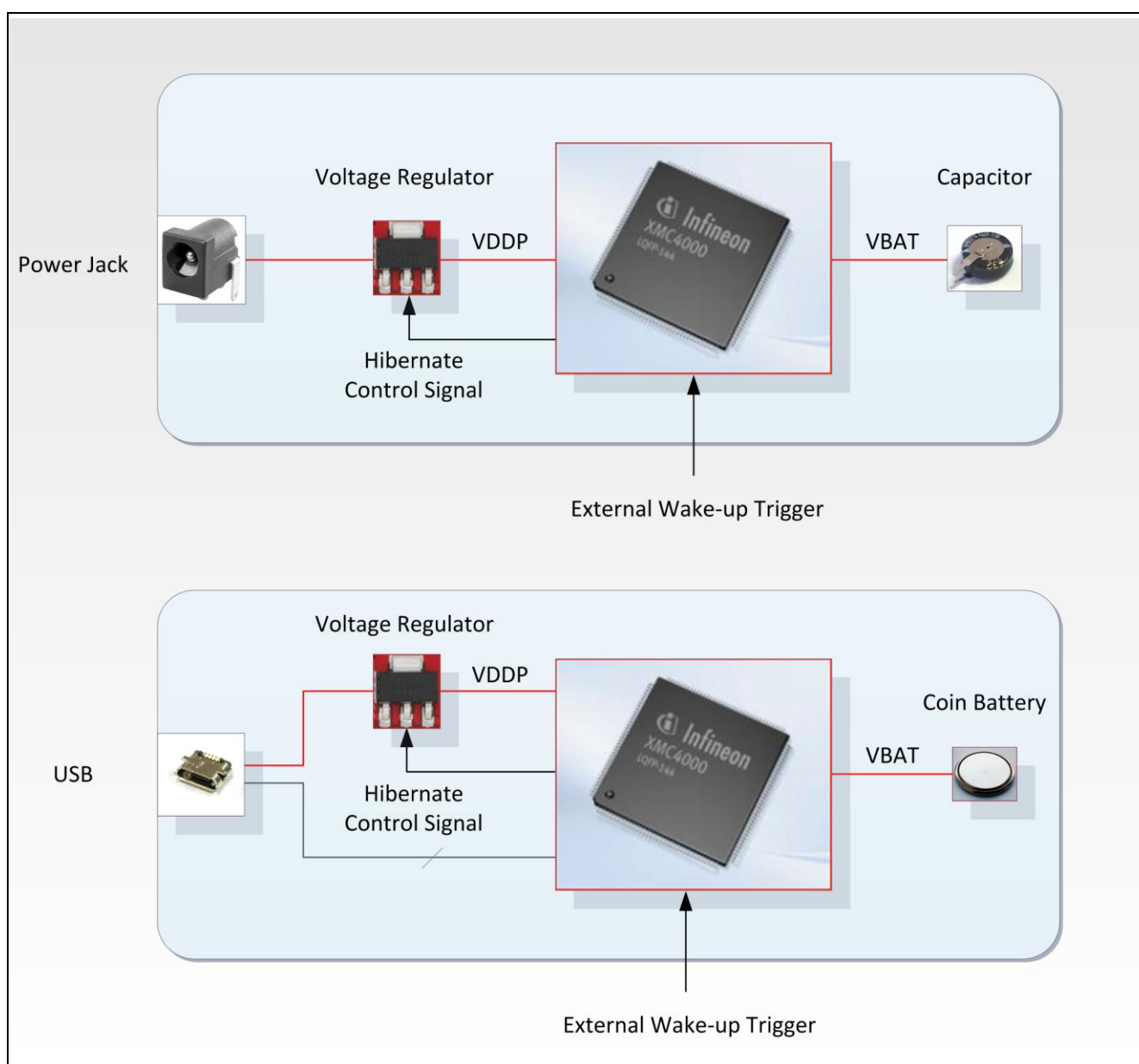


Figure 2 Examples of Externally Controlled Hibernate Mode use case

The external hibernate control is performed via the Hibernate Control Signal that will switch off the Voltage Regulator providing VDDP voltage to all components of the board. VBAT will still be supplied from an auxiliary source like e.g. a coin battery, or, a capacitor while in the Externally Controlled

Hibernate Mode. A wake-up trigger will come from an external source and/or from the internal RTC module.

1.2 Internally Controlled Hibernate Use Cases

Generic application scenarios of Internally Controlled Hibernate Mode are illustrated in Figure 3. These use case scenarios enable the XMC4000 to act as a system Power Control Slave. All system components in the VDDP power remain powered on while Core Domain of the XMC4000 device is powered off and I/Os are reset to input operation mode. Upon a wake-up trigger Core Domain of the XMC4000 will be powered-up and brought into operation.

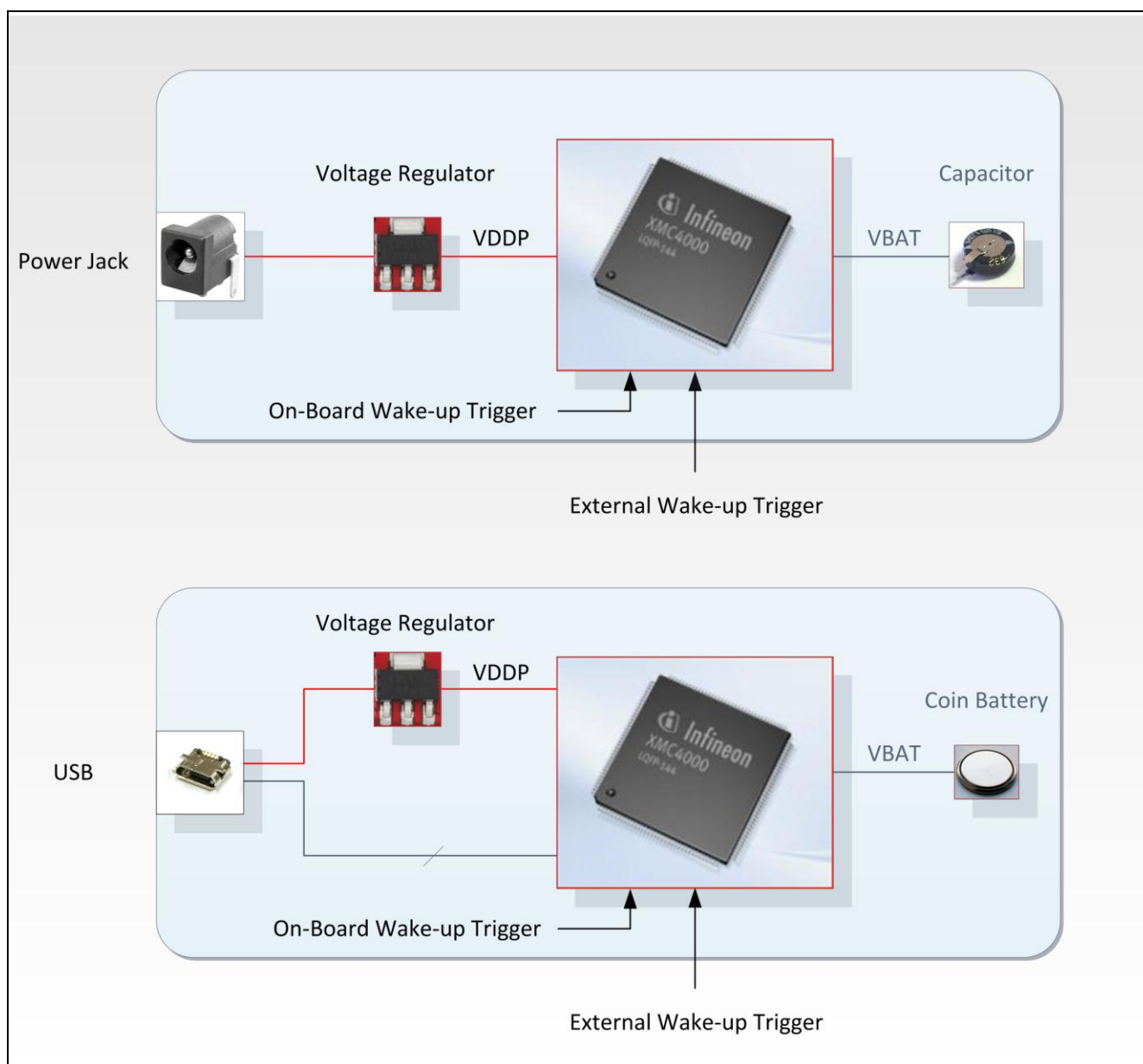


Figure 3 Examples of Internally Controlled Hibernate Mode use case

The internal hibernate control is performed via an internal circuit inside of the XMC4000 that will switch off the Embedded Voltage Regulator providing VDDC voltage to the Core Domain of the chip. While in Internally Controlled Hibernate Mode VBAT may still be supplied directly from the VDDP source while main supply is available, and/or from an auxiliary source like e.g. a coin battery, or, a

capacitor when the mains supply is off. A wake-up trigger will come from an external source and/or from the internal RTC module and will enable Core Domain voltage generation (if VDDP is still available).

Note: The Internally Controlled Hibernate Mode is not supported on XMC4500 device.

Hibernate Mode Implementations

2 Hibernate Mode Implementations

The two Hibernate Mode implementations, ECHM and ICHM, described in this section differ in the way the core voltage generation control mechanism. However, the wake-up trigger detection mechanism is the same for both Hibernate Mode implementations. The wakeup source can be digital or analog, internal (RTC event) or external (input signal on an I/O). For more details please refer to Table 1.

Table 1 **Hibernate Wake-up Triggers**

Trigger Source	I/O Signals	Description
RTC event	n/a	RTC Alarm or RTC Periodic Event.
Watchdog of RTC external crystal oscillator	n/a	The RTC external crystal oscillator (OSC_ULP) watchdog is capable of generating a wakeup trigger if the RTC clock generated with external crystal, or, a direct external clock stops unexpectedly
Digital Input Signal	HIB_IO_0 HIB_IO_1	Exclusive selection of one of the digital inputs. Depending of an application a rising and/or falling edge of the signal may be selected as a wake-up trigger. For external hibernate mode it is possible to combine Hibernate Control and Wake-up function in the same digital IO. For availability of the IOs please refer to the Data Sheet.
Analog Input Signal	HIB_IO_0 HIB_IO_1	Voltage threshold level crossing detection performed in the Low Power Comparator (LPAC) module. Depending of an application a rising and/or falling voltage event may be selected as a wake-up trigger. The level crossing detection can be performed continuously, periodically, or, may be triggered with an external digital signal. Multiple analog channels may be used for the wake-up trigger detection. For availability of the LPAC module please refer to the Data Sheet.
VBAT Supply Level Detection	VBAT	VBAT voltage detection can be performed with LPAC module. Depending of an application a rising and/or falling voltage event may be selected as a wake-up trigger. The VBAT input level can be performed continuously, periodically, or, triggered with an external digital signal. For availability of the LPAC module please refer to the Data Sheet.

Various combinations of wake-up triggers are possible and a wide range of possible applications is considered. The optimal selection of the Hibernate Mode and wake-up triggers application specific requirements and availability of resources need to be taken in consideration.

Some system topologies may combine capabilities of both implementation of the Hibernate Mode and can be applied interchangeably when required. However, only one of the Hibernate Modes can be applied at the time.

2.1 Externally Controlled Hibernate Mode Concept

The system configuration assumes that the XMC4000 device acts as the power management master of the system on PCB and is capable to switch off/on the external Voltage Regulator. The Hibernate Mode is entered by switching off the power supply VDDP of the device with the HIB_IO_0 pin. The HIB_IO_0 pin remains in control of the External Voltage Regulator after entering Hibernate Mode since entire Hibernate Domain remains supplied with the VBAT voltage from an auxiliary supply

voltage, e.g. a coin battery or a capacitor. A more detailed example scenario superset depicted in Figure 1 shows the components of the complete system that enable use of the Hibernate Mode.

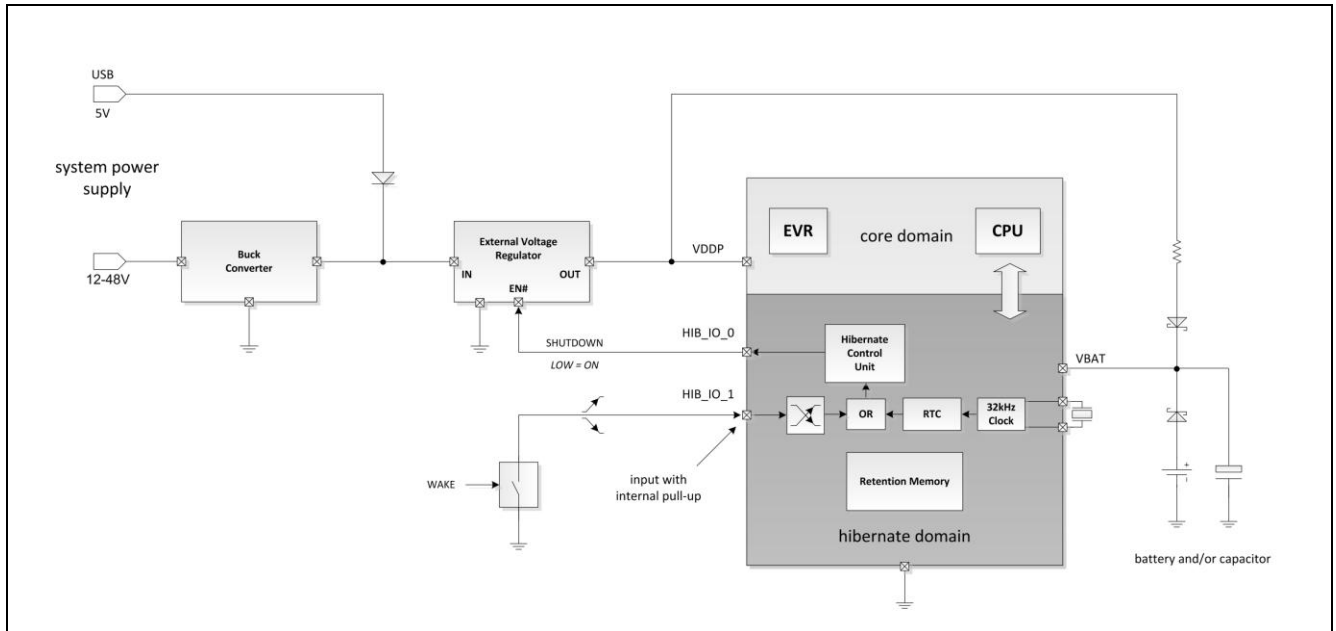


Figure 4 Externally Controlled Hibernate Mode Scenario

The Hibernate Control Unit (HCU) implements a circuit capable of controlling an External Voltage Regulator via an I/O and detecting occurrence of an event matching user programmed wake-up condition.

Entering Hibernate Mode is performed with a software request to a control register in the HCU module which results in toggling an I/O connected to the External Voltage regulator.

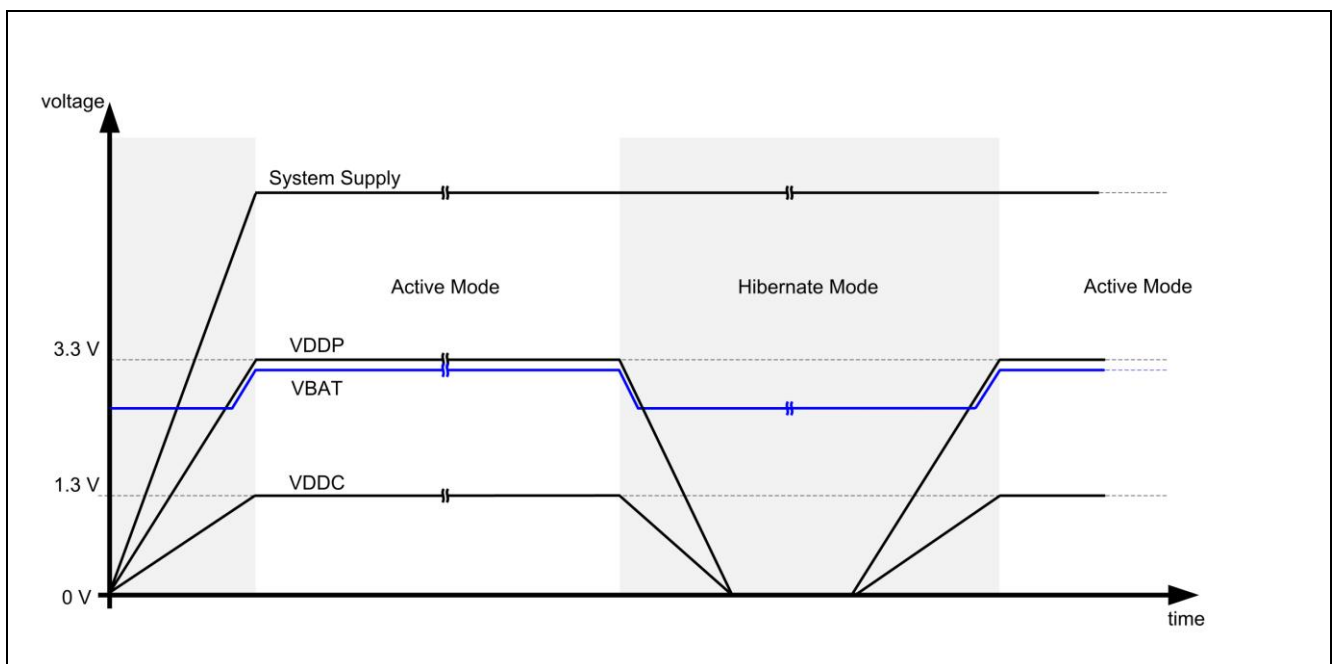


Figure 5 Externally Controlled Hibernate Mode Power Sequencing

A wake-up trigger may be an external input signal (digital, or, on some XMC4000 family members, also analog signal), or an RTC event. Upon a valid wake-up trigger the External Voltage Regulator gets enabled to generate VDDP which results in complete power-up sequence of the chip.

The scenario shown in Figure 2. illustrates voltage generation sequence upon entering and leaving Externally Controlled Hibernate. The main System Supply remains available on the PCB board. Upon entering Hibernate Mode the VDDP output of the External Voltage Regulator gets switched off, and, as consequence the Core Voltage of the XMC4000 (VDDC) is goes off. The VBAT voltage supplied from an auxiliary source remains available, although it may or may not have a different level than the valid VDDP supply level (for details please refer to Data Sheet).

Upon a wake-up from Hibernate Mode the VDDP generation in the External Voltage Regulator is restarted, and, also Core Domain voltage generation starts automatically. The VBAT voltage is supplied from VDDP via a (shottky) diode and may rise slightly if the VDDP has exceeded the voltage level from an auxiliary source.

2.2 Internally Controlled Hibernate Mode Concept

The Internally Controlled Hibernate Mode is entered by switching off internally the Core Domain VDDC voltage generation. After entering Hibernate Mode since entire Hibernate Domain remains supplied with the VBAT voltage, derived from VDDP, or, from an auxiliary supply voltage, e.g. a coin battery or a capacitor. A more detailed example scenario superset depicted in Figure 3. shows the components of the complete system that enable use of the Hibernate Mode.

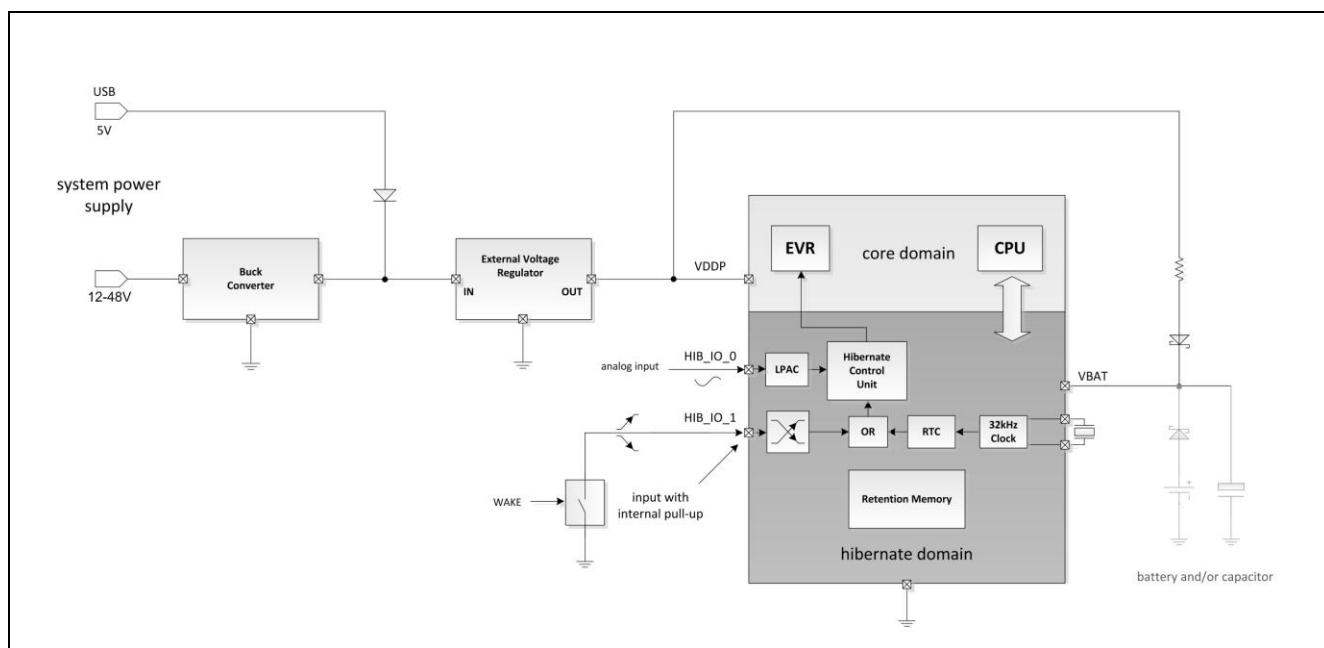


Figure 6 Internally Controlled Hibernate Mode Scenario

The Hibernate Control Unit (HCU) implements a circuit capable of controlling an Embedded Voltage Regulator (EVR) via a power separation cell and detecting occurrence of an event matching user programmed wake-up condition.

Entering Hibernate Mode is performed with a software request to a control register in the HCU module which results in switching off the EVR.

A wake-up trigger may be an external input signal (analog or digital), a VBAT monitoring event, or, an RTC event. Upon a valid wake-up trigger the EVR gets enabled to generate VDDC which results in complete power-up sequence of the chip.

The scenario shown in Figure 4. illustrates voltage generation sequence upon entering and leaving Internally Controlled Hibernate. The main System Supply and VDDP remain available on the application board. Upon entering Hibernate Mode the VDDC output of the EVR gets switched off, and, as consequence the Core Domain is powered off. The VBAT voltage supplied from an VDDP remains available.

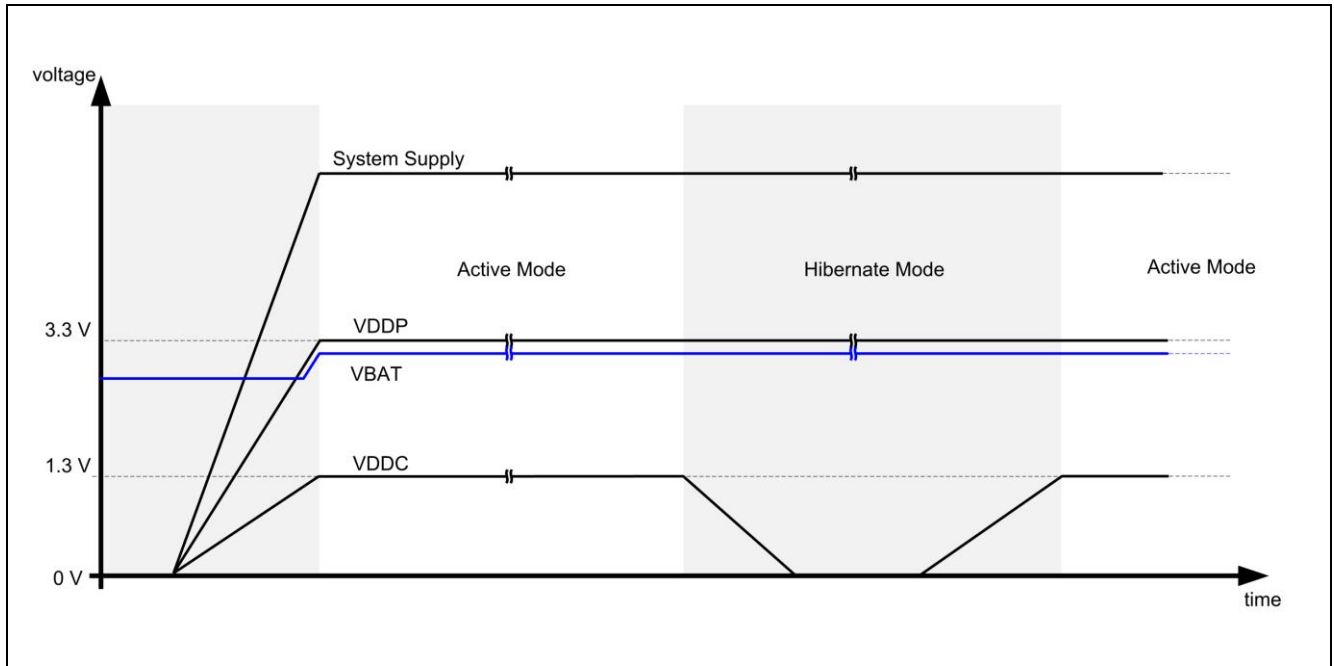


Figure 7 Internally Controlled Hibernate Mode Power Sequencing

Upon a wake-up from Hibernate Mode the VDDC generation in the EVR is restarted automatically. It is important to keep in mind that pads in the VDDP power domain remain supplied while in the Internally Controlled Hibernate Mode but are automatically reconfigured into input mode. The PORST reset gets activated (active low) and internal pull-up on the PORST reset pin gets automatically deactivated in order to minimize current consumption. After a wake-up trigger detection the pull-up on PORST gets activated, the PORST reset gets released as soon as the core voltage VDDC generation is restored.

Control of External Voltage Regulator

3 Control of External Voltage Regulator

Generally, External Voltage Regulators with on/off control input implement various control schemes and may impose special requirements on the voltage levels and driving strength of the control signal.

It needs to be noted that the hibernate control signals HIB_IO_0 and HIB_IO_1 implement different default driver configurations. This fact needs to be taken in account for PCB design and is determined by the selection of the External Voltage Regulator control scheme.

The HIB_IO_0 is configured as open drain driver and is driving level low after rest of the Hibernate Domain.

The HIB_IO_1 is configured to high impedance mode after reset of the Hibernate Domain and needs to be configured accordingly before used for hibernate control purpose.

Typically External Voltage Regulators are enabled with logic high level and disabled/shut down with logic low control signal. This kind of Voltage regulators may be controlled with a hibernate control I/O of XMC4000 device with an external pull-up resistor to a voltage that is equal or above the minimum required logic high level of the External Voltage Regulator.

The Table 1 provides a quick guidance for some implementations of the External Voltage Regulator control.

Table 2 External Voltage Regulator Control Scheme Guidance

External Voltage Regulator Control Scheme	Enable Signal Level/Control IO	Features/Hits
Active high enable via pull-up	high/HIB_IO_1	<ul style="list-style-type: none"> One pull-up resistor on PCB required Very low current consumption from V_{BAT} source Suitable for use with a golcap as V_{BAT} source
Active high enable driven from a voltage divider	high/HIB_IO_1	<ul style="list-style-type: none"> Two pull-up resistors on PCB required Very low current consumption from V_{BAT} source Suitable for use with a golcap as V_{BAT} source Wake-up triggered while
Active low enable driven with push-pull I/O	low/HIB_IO_0	<ul style="list-style-type: none"> Simple, no external components on PCB required Higher Voltage on V_{BAT} source may be required Extra current drained from V_{BAT} source Not suitable for use with a goldcap as V_{BAT} source
Active low enable and with pull-up to high	low/HIB_IO_0	<ul style="list-style-type: none"> One pull-up resistor on PCB required Very low current consumption from V_{BAT} source Possible control and wake-up trigger on one pin Suitable for use with a golcap as V_{BAT} source
Active low enable driven from a voltage divider	low/HIB_IO_0	<ul style="list-style-type: none"> Two pull-up resistors on PCB required Very low current consumption from V_{BAT} source Possible control and wake-up trigger on one pin Suitable for use with a golcap as V_{BAT} source External wake-up detection supply failure tollerant
Active low enable driven from a voltage divider and V_{BAT}	low/HIB_IO_0	<ul style="list-style-type: none"> Two pull-up resistors and 2 diodes on PCB required Very low current consumption from V_{BAT} source Possible control and wake-up trigger on one pin Suitable for use with a golcap as V_{BAT} source External wake-up detection supply failure tollerant

3.1 Active high enable via pull-up

A simple implementation of the scheme is illustrated in the Figure 1. The voltage V_{CTRL} connected to the EN pin of the External Voltage Regulator via the pull-up resistor R1 in order to drive level high. The hibernate control signal, configured as open drain driver, is in high impedance state when high is driven from the Hibernate Control Unit. When the hibernate control signal is driving level low, the pull-up driving V_{CTRL} gets overcome with the strong driver inside the XMC4000 device. The V_{CTRL} is assumed to fulfill the requirement:

$$V_{EN\ min} \leq V_{CTRL} \leq V_{EN\ max}$$

where the $V_{EN\ min}$ and $V_{EN\ max}$ are the minimum and maximum control input voltage levels for the External Voltage Regulator, respectively.

In typical case the Supply Voltage is suitable to drive the EN control input high (for details please refer to specification of the External Voltage Regulator). The V_{CTRL} may also be supplied from VBAT, but it may lead e.g. to a coin shorter battery life or quicker discharge of a capacitor supplying Hibernate Domain while in Hibernate Mode, therefore in most application scenarios should be avoided.

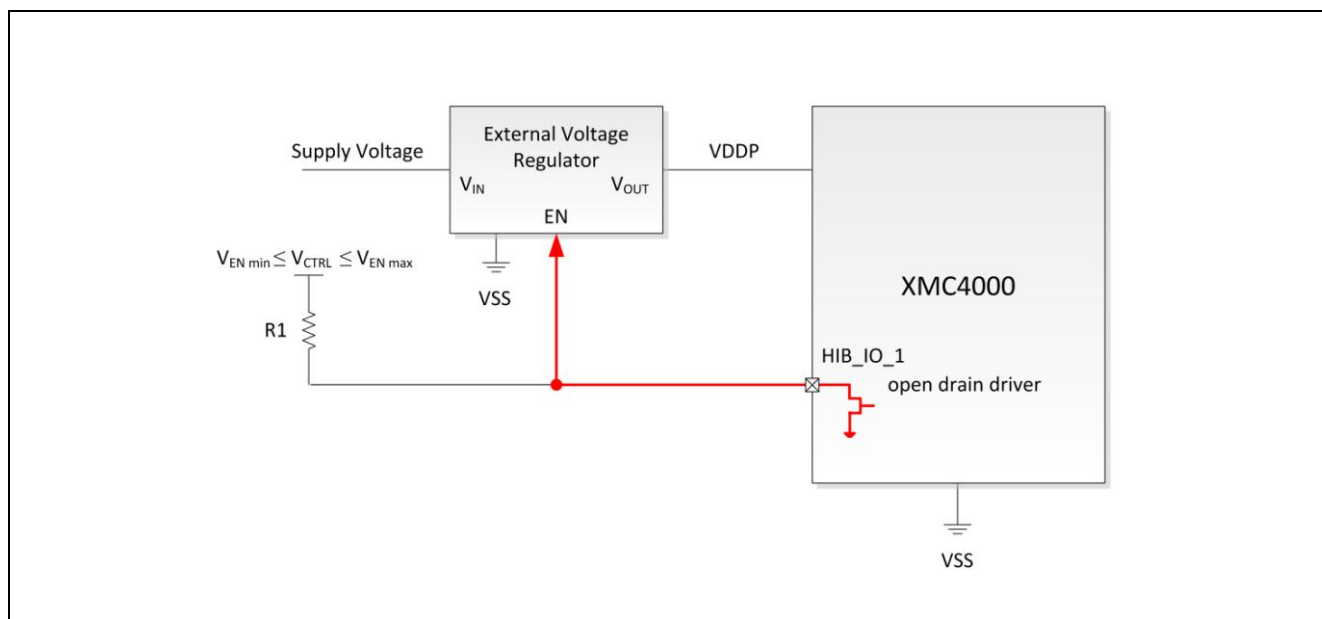


Figure 8 External Voltage Regulator with active high enable via pull-up

For applications where the External Voltage Regulator is active when the control signal is high it is required to use the HIB_IO_1 I/O as the hibernate control signal in order to ensure reliable start of the device after reset of the hibernate domain, as illustrated in Figure 2. After Hibernate Domain reset the HIB_IO_1 signal is in high impedance state and the External Voltage Regulator will control input is driven high via the R1 pull-up resistor which enables VDDP voltage generation and start of the system.

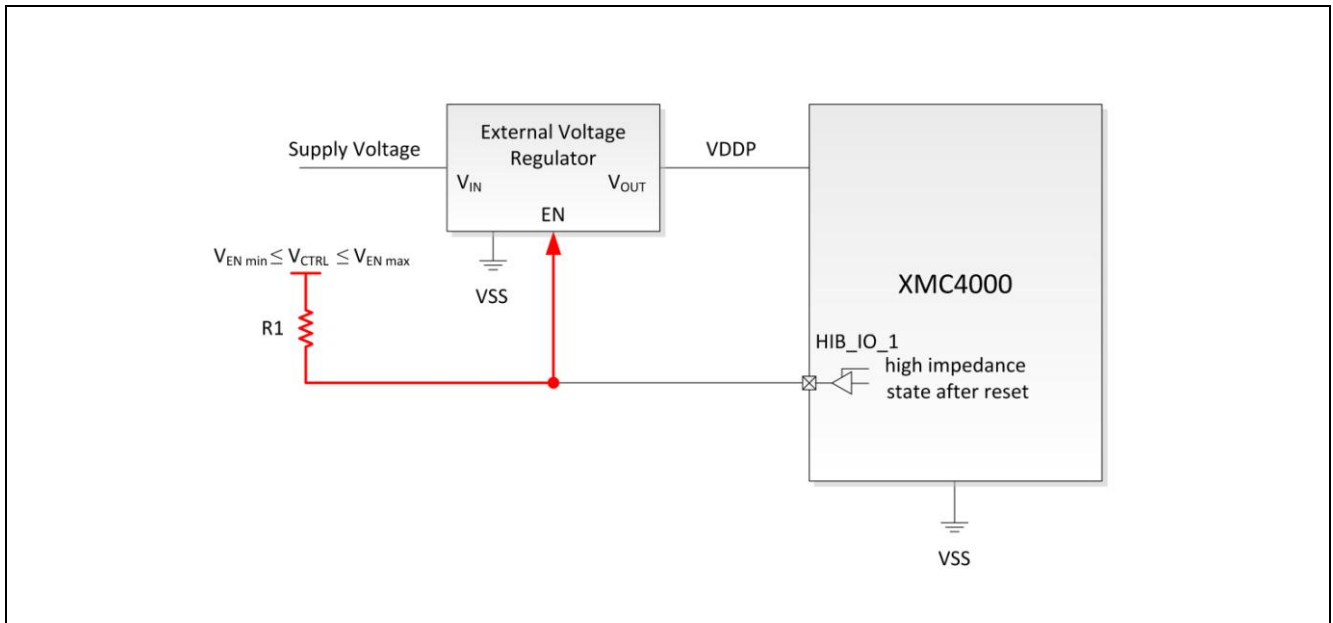


Figure 9 External Voltage Regulator with active high enable via pull-up after reset

3.2 Active high enable driven from a voltage divider

In case a high level of the EN control signal of the External Voltage Regulator cannot be driven using a simple pull-up it may be necessary to generate a suitable voltage source. This can be realized with a resistive voltage divider apply a voltage as illustrated in Figure 3.

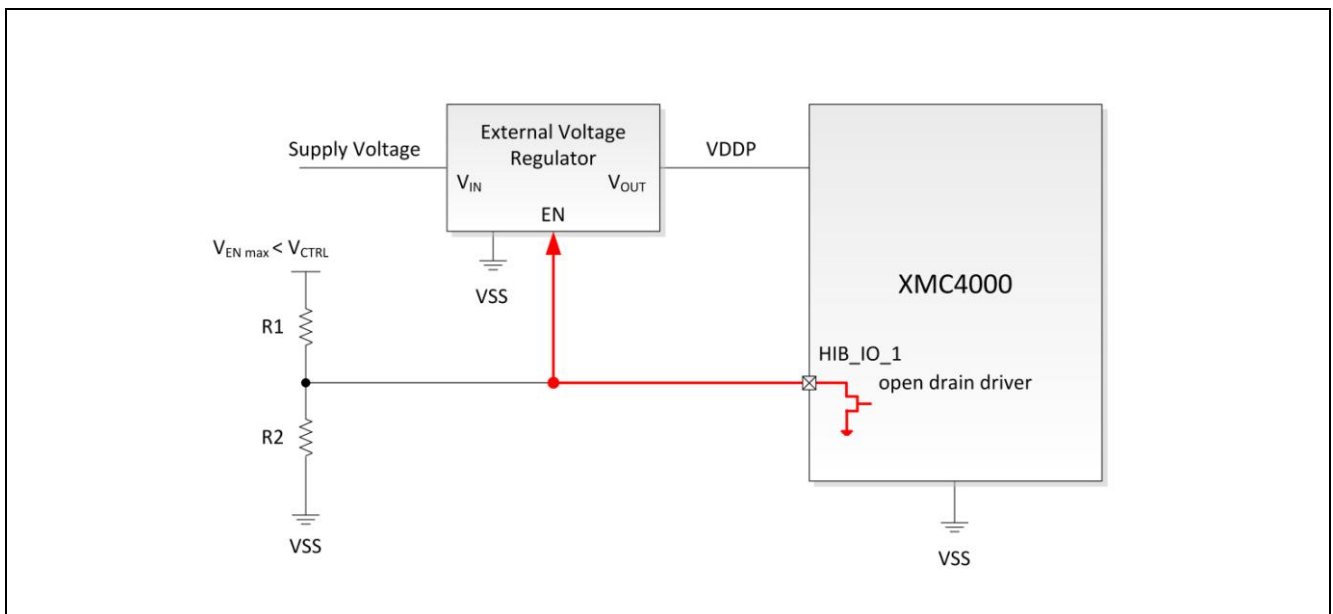


Figure 10 External Voltage Regulator with active high enable from a voltage divider

This solution allows applying V_{CTRL} voltage:

$$V_{EN\ max} \leq V_{CTRL}$$

where the $V_{EN\ min}$ maximum control input voltage level for the External Voltage Regulator.

The values of the R1 and R2 resistors of the voltage divider shall be possibly high in order to enable to the HIB_IO_1 signal to override with signal level low when driven with the open drain driver.

A potential advantage of this topology is that the V_{CTRL} used to generate the enable signal for the External Voltage Regulator may be independent from its Supply Voltage. This may be useful if the Supply Voltage of the External Voltage Regulator gets lowered while in Hibernate Mode and a valid wake-up trigger gets detected. The enable signal driven to the External Voltage Regulator will also reach a valid level, i.e. above the $V_{EN\ min}$.

3.3 Active low enable driven with push-pull I/O

In case of a low enabled External Voltage Regulator the control scheme is largely simplified and may be realized with direct connection from push-pull I/O driver of the XMC4000 device, without additional components on the PCB. This scheme requires that the HIB_IO_0 pin is used as the control signal because it's by default configured as default open drain driver, allowing startup of the system after Hibernate Domain has been reset, which is the case after initial power up. After startup of the system the HIB_IO_0 needs to be reconfigured to push-pull driving mode.

This configuration requires that the following condition is fulfilled:

$$V_{EN\ min} \leq V_{BAT} \leq V_{EN\ max}$$

where the $V_{EN\ min}$ and $V_{EN\ max}$ are the minimum and maximum control input voltage levels for the External Voltage Regulator, respectively, V_{BAT} is the supply voltage of the Hibernate Domain.

While in Hibernate Mode the current required to drive the #EN control input of the External Voltage Regulator is drained from VBAT source and it needs to be taken in account that it may result e.g. in a shorter life of a coin battery. Use of a capacitor may be limited due to potentially narrow range of the EN signal voltage range. It may be difficult to maintain the required voltage level in the capacitor over a longer period of Hibernate Mode.

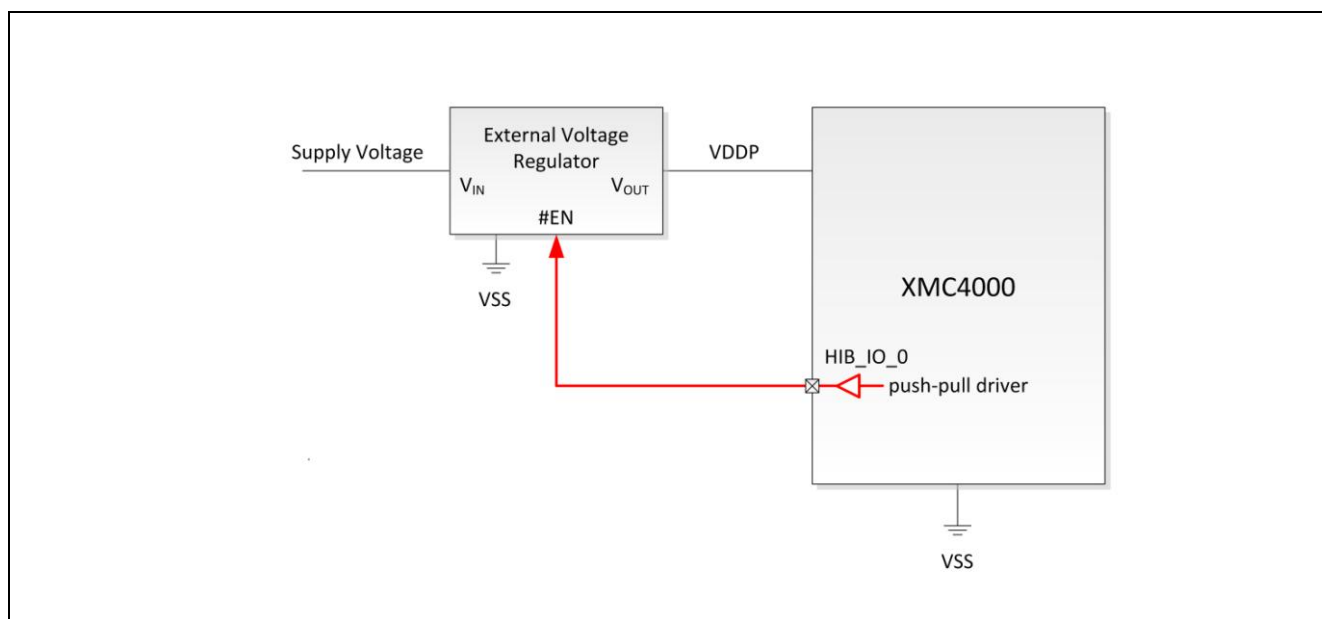


Figure 11 External Voltage Regulator with active low direct enable

3.4 Active low enable and with pull-up to high

Another flavor of the configuration with a low enable capable External Voltage Regulator assumes a pull-up to a V_{CTRL} voltage in order to drive #EN high, as depicted in Figure 5. The following condition must be fulfilled for the V_{CTRL} voltage:

$$V_{EN\ min} \leq V_{CTRL} \leq V_{EN\ max}$$

where the $V_{EN\ min}$ and $V_{EN\ max}$ are the minimum and maximum control input voltage levels for the External Voltage Regulator, respectively.

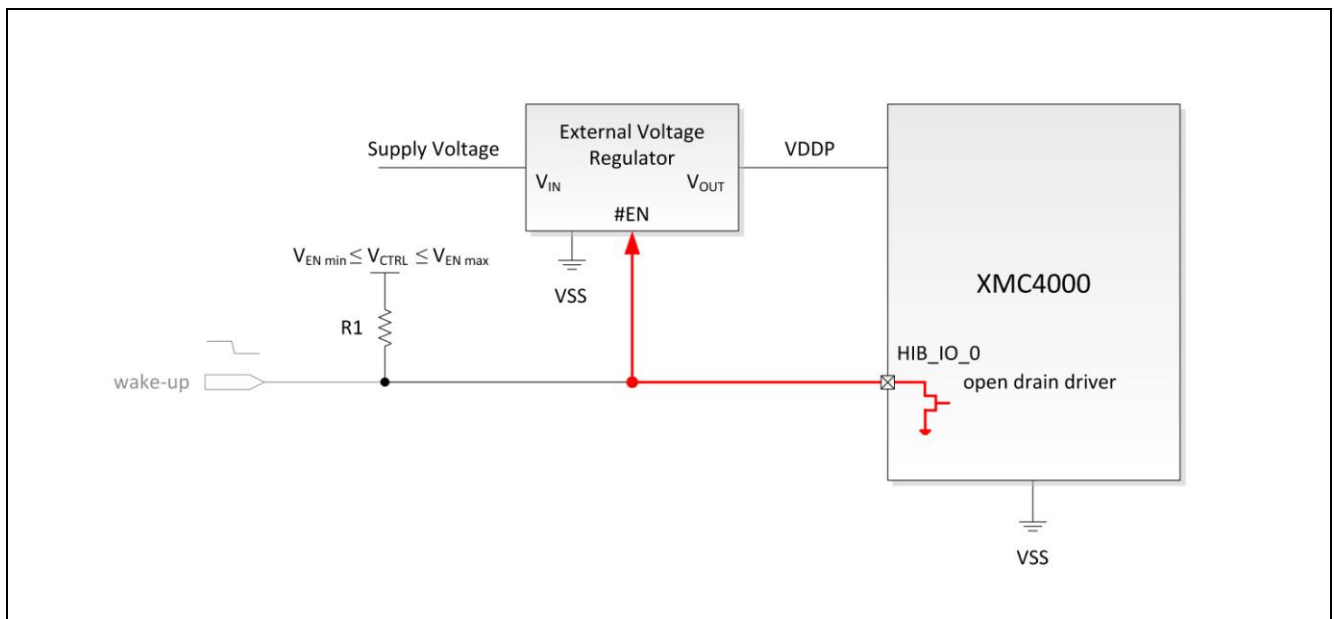


Figure 12 External Voltage Regulator with active low enable via a pull-up

This configuration offers attractive power consumption feature while in Hibernate Mode if the V_{CTRL} is supplied e.g. from the Supply Voltage. The current drained on the #EN input of the External Voltage Regulator while in Hibernate Mode does not discharge the V_{BAT} source e.g. a coin battery. Moreover, the control function of the HIB_IO_0 pin can also be combined with a wake-up trigger function on negative edge. The control signal high can be overridden by a signal low from a stronger (open drain) driver, creating a negative signal edge.

3.5 Active low enable driven from a voltage divider

In case a high level of the #EN control signal of the External Voltage Regulator cannot be driven using a simple pull-up it may be necessary to generate a suitable voltage source. This can be realized with a resistive voltage divider apply a voltage as illustrated in Figure 6.

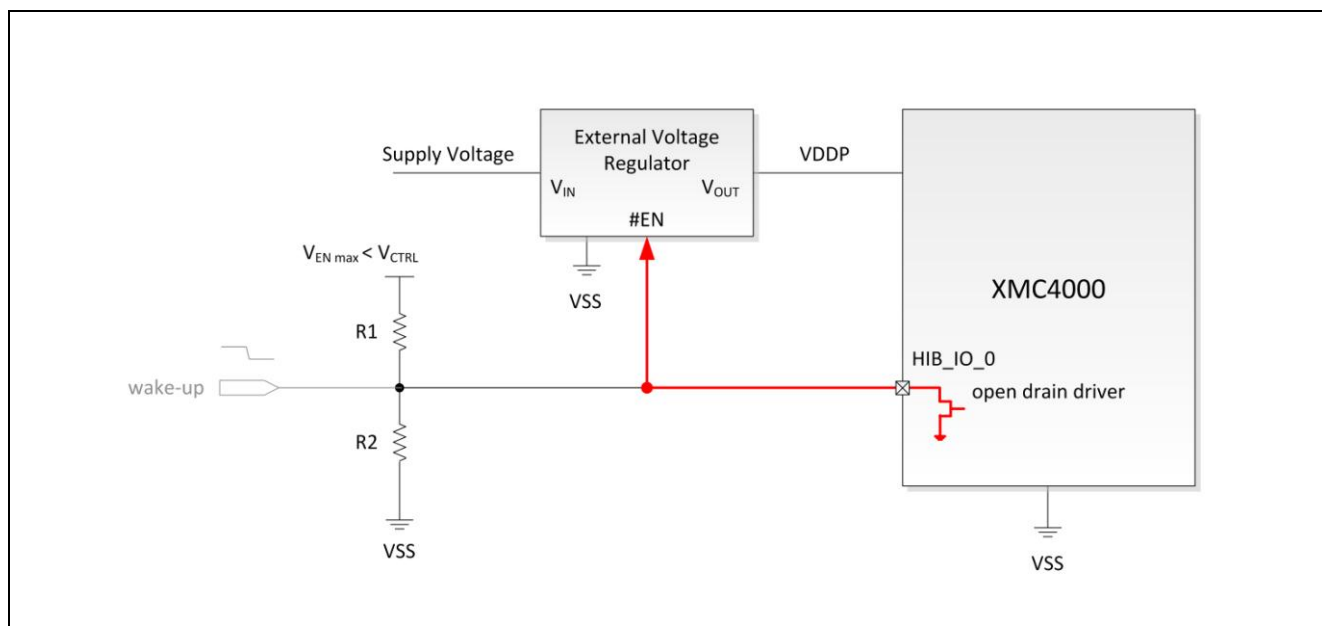


Figure 13 External Voltage Regulator with active low enable from a voltage divider

This solution allows to apply V_{CTRL} voltage:

$$V_{EN\ max} \leq V_{CTRL},$$

where the $V_{EN\ min}$ maximum control input voltage level for the External Voltage Regulator.

The values of the R1 and R2 resistors of the voltage divider shall be possibly high in order to enable to the HIB_IO_0 signal to override with signal level low when driven with the open drain driver.

A potential advantage of this topology is that the V_{CTRL} used to generate the enable signal for the External Voltage Regulator may be independent from its Supply Voltage. This may be useful if the Supply Voltage of the External Voltage Regulator gets lowered while in Hibernate Mode and the HIB_IO_0 I/O is also serving input purpose for an external wake-up trigger. The wake-up trigger (negative edge) will get detected reliably since it will reach a valid level. This implies also that enable signal driven to the External Voltage Regulator will also reach a valid level, i.e. above the $V_{EN\ min}$. This may not result in immediate wake-up and proper power up of the XMC4000 device is the Supply Voltage remain below the minimum level to generate a valid VDDP (for details please refer to Data Sheet) but the wake-up will eventually occur when the supply condition has improved.

3.6 Active low enable driven from a voltage divider and V_{BAT}

A more complex topology shown in Figure 7 offers a superset combination of the features described in previous paragraphs. The External Voltage Regulator control is combined with a wake-up trigger (falling edge) on the HIB_IO0 I/O of the XMC4000 device. The #EN signal gets generated with the pull-up resistor to the Supply Voltage of the External Voltage Regulator. The wake-up trigger detection will function reliably also when the Supply Voltage drops down below a minimum level of the V_{BAT} voltage and will effectively bring up the system into operation as soon as the proper Supply Voltage is restored.

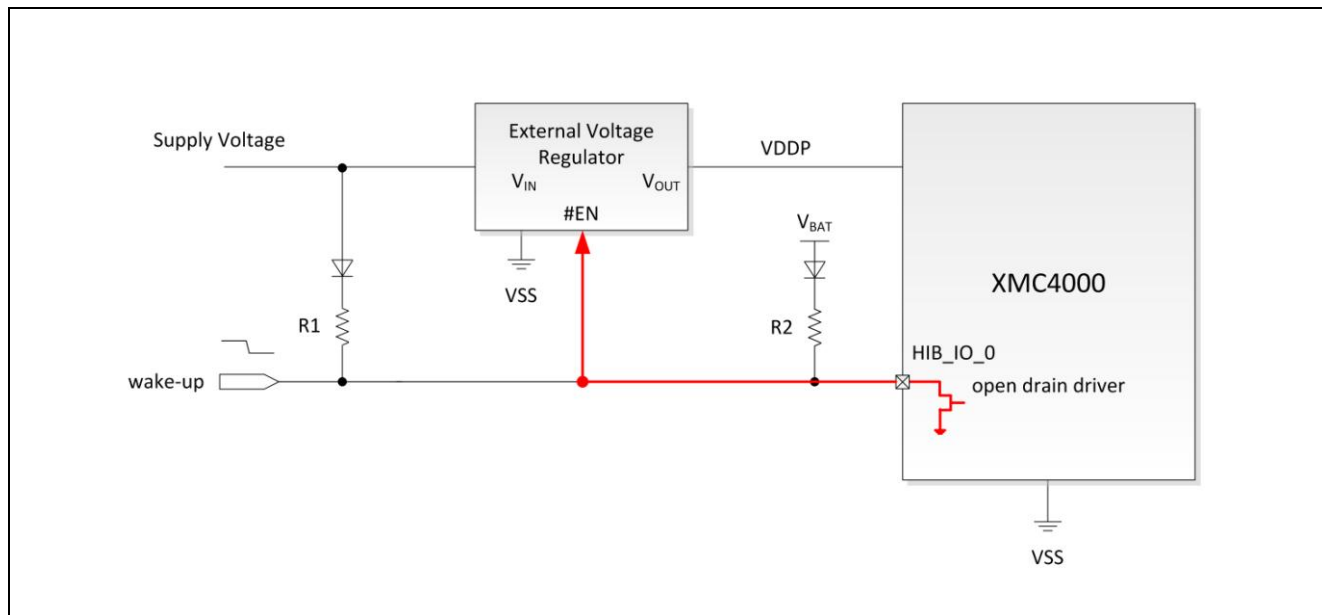


Figure 14 External Voltage Regulator with active low enable from a voltage divider

The following condition must be fulfilled for the V_{CTRL} voltage:

$$V_{EN\ min} \leq V_{CTRL} \leq V_{EN\ max}$$

where the $V_{EN\ min}$ and $V_{EN\ max}$ are the minimum and maximum control input voltage levels for the External Voltage Regulator, respectively.

Getting Started

4 Getting Started

The Flowchart in the Figure 1 shows the generic sequence of actions required to enter and wake-up from a Hibernate Mode. It is assumed that the system on PCB implements a superset of resources required to make use of any of the Hibernate Modes (example topology that may be applicable here can be found in the Figure 2)

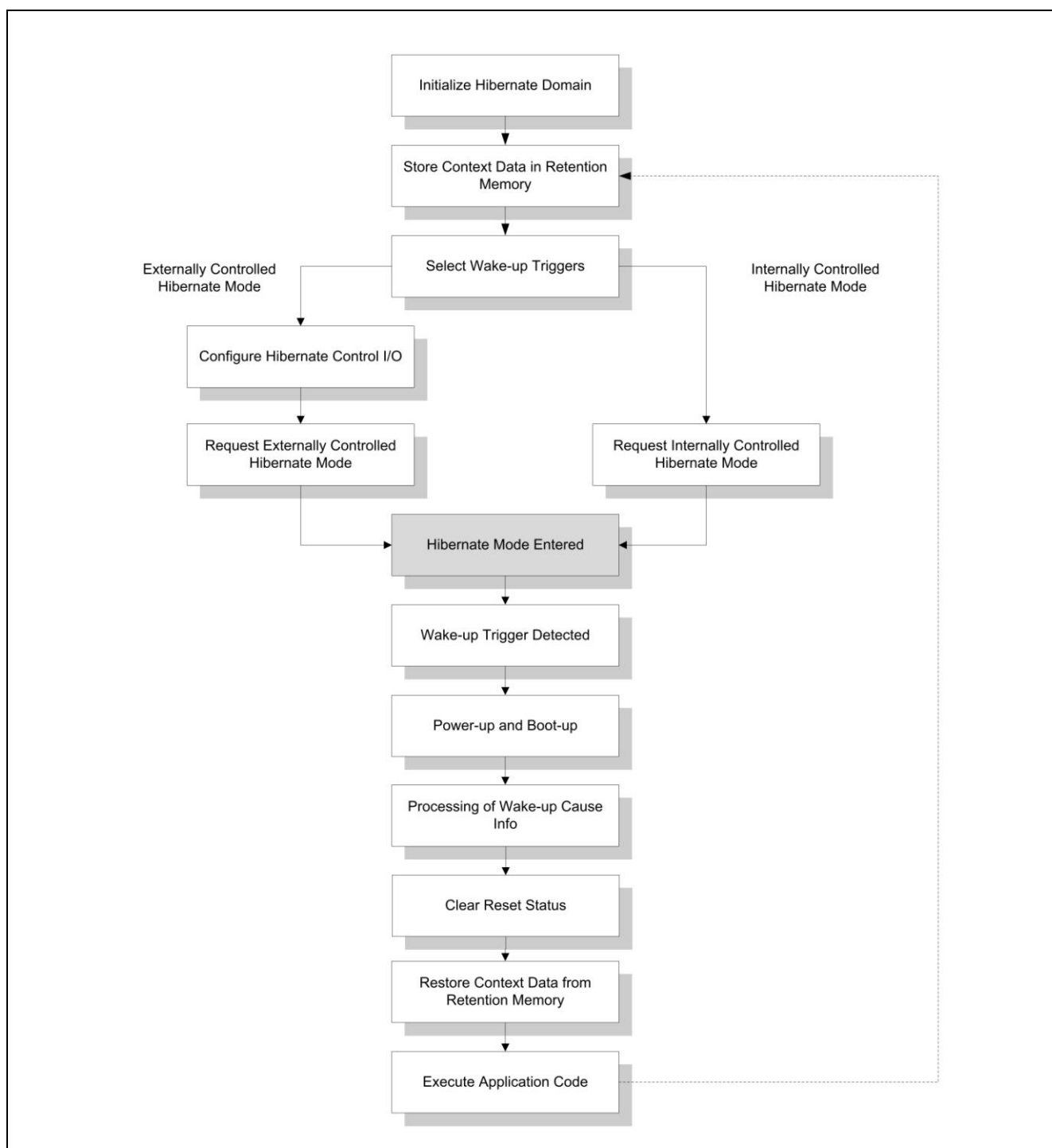


Figure 15 Hibernate Sequence

The Hibernate Mode control register located in the Hibernate Control Unit can be accessed via mirror registers. Before writing to any of the registers it is required to check if the corresponding status bits in the SCU_MIRRSTS register indicate that a new access can be accepted.

4.1 Initialize Hibernate Domain

The Hibernate Domain needs to be enabled and/or released from reset state before it can be used. Typically, this needs to be done after power-up of the Hibernate Domain. This step may be omitted if the Hibernate Domain is already initialized.

- Enable Hibernate Domain

Set bit SCU_PWRSET.HIB

- Release reset of Hibernate Domain (if asserted)

Clear bit SCU_RSTCLR.HIBRS

- Enable and configure Ultra Low Power Oscillator if a high precision clock required

Configure SCU_OSCULCTRL.MODE

Note: startup of the RTC external crystal oscillator may take some, please refer to Data Sheet for details

- Select the clock source and start RTC if Real Time Clock required.

Select clock in SCU_HDCR.RCS

- Set current time in RTC

Write to registers RTC.TIM0 and RTC.TIM1

- Enable RTC module with RTC_CTR register

Set bit RTC_CTR.ENB

Example pseudo-code:

```
//Enable Hibernate Domain
SCU_POWER->PWRSET = 0x1 << SCU_POWER_PWRSET_HIB_Pos;

//Release Hibernate Domain from reset state
SCU_RESET->RSTCLR = 0x1 << SCU_RESET_RSTCLR_HIBRS_Pos;

//Enable RTC external clock oscillator
```

```

SCU_HIBERNATE->OSCULCTRL &= ~SCU_HIBERNATE_OSCULCTRL_MODE_Msk;

//Select external crystal oscillator as RTC clock source
//wait until HDCR register ready for a write
do {
}
while ( SCU_GENERAL->MIRRSTS & SCU_GENERAL_MIRRSTS_HDCR_Msk);

//write 1 to SCU_HDCR.RCS
SCU_HIBERNATE->HDCR &= (~SCU_HIBERNATE_HDCR_RCS_Msk) | (0x1 << SCU_HIBERNATE_HDCR_RCS_Pos);

//wait around 10 ms
wait (10);

//Program RTC time
//wait until RTC.TIM0 and RTC.TIM1 ready for a write

do {
}
while ( SCU_GENERAL->MIRRSTS & \
(SCU_GENERAL_MIRRSTS_RTC_TIM0_Msk | SCU_GENERAL_MIRRSTS_RTC_TIM0_Msk1));

//write to TIM0 and TIM1
RTC->TIM0 = time_day_hours_minutes_seconds;
RTC->TIM1 = time_years_months_days_day_of_week;

//start RTC counter
RTC->CTR |= 0x1 << RTC_CTR_ENB_Pos;

```

4.2 Store Context Data in Retention Memory

The application context specific data can be optionally stored in the Retention Memory in Hibernate Domain for a later use, i.e. after a wake-up. The Retention Memory can be accessed via dedicated Mirror Registers. The Retention Memory is comprised of 16 x 32-bit registers.

Write data to SCU_RMDATA register and Issue a write command with SCU_RMCCR.

Examine the mirror status register bit SCU_MIRRSTS.RMX before each write to SCU_RMCCR and make sure that no new write is performed before it has been cleared.

This step may also be specific to an Operating System.

Example pseudo-code:

```

//Write data to address 0x4 of the Retention Memory
//store a write data for a write to retention memory in SCU_RMDATA register
SCU_GENERAL->RMDATA = data;

//wait until RMCCR register ready for a write command
do {
}
while ( SCU_GENERAL->MIRRSTS & SCU_GENERAL_MIRRSTS_RMX_Msk);

//write data to address 0x4
SCU_GENERAL->RMCCR = (0x4 << SCU_GENERAL_RMCCR_ADDR_Pos) | (0x1 << SCU_GENERAL_RMCCR_RDWR_Pos);

```

4.3 Select Wake-up Triggers

Various kinds of trigger may be selected to wake-up the system from a hibernate mode, see Table 1. For availability of the wake-up sources please refer to Data Sheet of the device.

- RTC event

Select RTC wake up event with SCU_HDCR.RTCE

Configure RTC periodic event (if required) with RTC_CTR register

Configure RTC alarm with RTC_ATIM0 and RTC_ATIM1 registers and enable with RTC_CTR.TAE

Clear RTC event status bit with SCU_HDCLR.RTCEV

- Watchdog of RTC external crystal oscillator

Select the watchdog event as a wake-up trigger with SCU_HDCR.ULPWDGEN

Clear the watchdog trigger status with SCU_HDCLR.ULPWDG

- Trigger on a digital I/O

Select trigger active edge with SCU_HDCR.WKPEP and with SCU_HDCR.WKPEN

Select a digital I/O as the digital trigger input with SCU_HDCR.WKUPSEL

Configure digital I/O input properties with SCU_HDCR.HIBIO0SEL or SCU_HDCR.HIBIO1SEL

Clear the Digital Input Signal trigger status with SCU_HDCLR.EPEV

Clear the Digital Input Signal trigger status with SCU_HDCLR.ENEV

- Trigger on analog I/Os

Initialize/configure the LPAC module, select analog channels, set thresholds

Select wakeup on HIB_IO_0 negative threshold crossing with SCU_HDCR.AHIBIO0LO

Select wakeup on HIB_IO_0 positive threshold crossing with SCU_HDCR.AHIBIO0HI

Select wakeup on HIB_IO_1 negative threshold crossing with SCU_HDCR.AHIBIO1LO

Select wakeup on HIB_IO_1 positive threshold crossing with SCU_HDCR.AHIBIO1HI

Configure analog I/O input properties with SCU_HDCR.HIBIO0SEL or SCU_HDCR.HIBIO1SEL

Clear the analog HIB_IO_0 Input Signal trigger status with SCU_HDCLR.HIBIO0LO

Clear the analog HIB_IO_0 Input Signal trigger status with SCU_HDCLR.HIBIO0HI

Clear the analog HIB_IO_1 Input Signal trigger status with SCU_HDCLR.HIBIO1LO

Clear the analog HIB_IO_1 Input Signal trigger status with SCU_HDCLR.HIBIO1HI

- VBAT Supply Level Detection

Initialize/configure the LPAC module, select analog channels, set thresholds

Select wakeup on a VBAT negative threshold crossing with SCU_HDCR.VBATLO

Select wakeup on a VBAT positive threshold crossing with SCU_HDCR.VBATHI

Clear the analog Input Signal trigger status with SCU_HDCR.VBATLO

Clear the analog Input Signal trigger status with SCU_HDCR.VBATHI

Example pseudo-code:

```
//wait until SCU_HDCR register ready for a write

do {
    } while ( SCU_GENERAL->MIRRSTS & SCU_GENERAL_MIRRSTS_HDCR_Msk);

//write 1 to HDCR.RTCE in order to enable wake-up on RTC event

SCU_HIBERNATE->HDCR &= (~SCU_HIBERNATE_HDCR_RTCE_Msk) | (0x1 << SCU_HIBERNATE_HDCR_RTCE_Pos);

//wait until SCU_HDCR register ready for a write

do {
    } while ( SCU_GENERAL->MIRRSTS & SCU_GENERAL_MIRRSTS_HDCR_Msk);

//write 1 to HDCR.WKPEN in order to enable wake-up on negative edge of a digital
//input

SCU_HIBERNATE->HDCR &= (~SCU_HIBERNATE_HDCR_WKPEN_Msk) | (0x1 << SCU_HIBERNATE_HDCR_WKPEN_Pos);
```

Note: All the consecutive writes to the SCU_HDCR register above can be combined in a single write of a multiple bits to the SCU_HDCR register

4.4 Configure Hibernate Control I/O

- Digital outputs polarity

Configure digital I/O output polarity with SCU_HDCR.HIBIO0POL or SCU_HDCR.HIBIO1POL

- Select hibernate control output and driver properties

Configure digital I/O output properties with SCU_HDCR.HIBIO0SEL or SCU_HDCR.HIBIO1SEL

Example pseudo-code:

```
//wait until SCU_HDCR register ready for a write

do {
    } while ( SCU_GENERAL->MIRRSTS & SCU_GENERAL_MIRRSTS_HDCR_Msk);

//write 1 to HDCR.HIBPOL0 in order to ensure that External Voltage Regulator
//control signal is low when Externally Controlled Hibernate is activated via
//HIB_IO_0 pin
```

```
SCU_HIBERNATE->HDCR &= (~SCU_HIBERNATE_HDCR_HIBPOL0_Msk) | (0x1 << SCU_HIBERNATE_HDCR_HIBPOL0_Pos);

//wait until SCU_HDCR register ready for a write
do {
    } while ( SCU_GENERAL->MIRRSTS & SCU_GENERAL_MIRRSTS_HDCR_Msk);

//write 0xC to HDCR.HIBIO0SEL in order to configure the HIB_IO_0 I/O as open drain
//driver

SCU_HIBERNATE->HDCR    &=    (~SCU_HIBERNATE_HDCR_HIBIO0SEL_Msk)    |    (0xC    <<    SCU_HIBERNATE_HDCR_
HIBIO0SEL_Pos);
```

Note: All the consecutive writes to the SCU_HDCR register above can be combined in a single write of a multiple bits to the SCU_HDCR register

4.5 Request External Hibernate Mode

- Request Hibernate Mode

Set SCU_HDCR.HIB

- Wait for hibernate to take effect

Prevent casual code execution, e.g. stay in an endless loop or idle process (in case of an Operating System)

Example pseudo-code:

```
//wait until SCU_HDCR register ready for a write
do {
    } while ( SCU_GENERAL->MIRRSTS & SCU_GENERAL_MIRRSTS_HDCR_Msk));

//write 1 to HDCR.HIB
SCU_HIBERNATE->HDCR &= (~SCU_HIBERNATE_HDCR_HIB_Msk) | (0x1 << SCU_HIBERNATE_HDCR_HIB_Pos);

//stay in endless loop
while (1){};
```

Note: All the consecutive writes to the SCU_HDCR register can be combined in a single write of a multiple bits to the SCU_HDCR register

4.6 Request Internal Hibernate Mode

- Request Hibernate Mode

Set SCU_HINSET.HIBNINT

- Wait for hibernate to take effect

Prevent casual code execution, e.g. stay in an endless loop or idle process (in case of an Operating System)

Example pseudo-code:

```
//wait until SCU_HITSET register ready for a write
do {
    } while ( SCU_GENERAL->MIRRSTS & SCU_GENERAL_MIRRSTS_HINTSET_Msk);

//write 1 to SCU_HINSET.HIBNINT
SCU_HIBERNATE->HINTSET = (0x1 << SCU_HIBERNATE_HINTSET_HIBINT_Pos);

//stay in endless loop
while (1){};
```

4.7 Hibernate Mode Entered

Hibernate Mode has been entered; no software is running on CPU, entire core domain Core Domain is in power-off state. Hibernate domain is waiting for a wake-up trigger.

- Externally Controlled Hibernate Mode

VDDP supply removed,
Pads (except for Hibernate domain pads) powered off

- Internally Controlled Hibernate Mode

VDDP supply present,
Pads (except for the Hibernate domain pads) in input mode,
PORST reset asserted
VDDC generation disabled

4.8 Wake-up Trigger Detected

A valid wake-up trigger event detected in the Hibernate Control Unit (HCU), wake-up process starting. No user code involved, handled in hardware.

- Externally Controlled Hibernate Mode

Hibernate Control I/O (HIB_IO_0 or HIB_IO_1)) toggling in order to enable External Voltage Regulator to start generation of VDDP

- Internally Controlled Hibernate Mode

Control signal to EVR generated in order to start VDDC generation

4.9 Power-up and Boot-up

No user code involved, handled in hardware and Firmware

- Power of the chip restored
- Resets released
- Execution of the Firmware (Boot-up code)

4.10 Processing of Wake-up Cause Info

- Detection of a wakeup from Hibernate mode

Examine the SCU_RSTSTAT.HIBWK

- Detection of the last reset cause

Examine (optionally) the SCU_RSTSTAT.RSTSTAT in order to determine if the last reset was caused by power-off

- Detection of the source wake-up trigger

Examine the wake-up trigger source in SCU_HDSTAT register bit fields.

Example pseudo-code:

```
//Read and interpret wake-up info from SCU_RSTSTAT.HIBWK
If (SCU_RESET->RSTSTAT.HIBWK)
{
    wakeup_occured_flag = true;
}
else
{
    wakeup_occured_flag = false;
}

//Read and interpret wake-up info from SCU_RSTSTAT.RSTSTAT
reset_cause = SCU_RESET->RSTSTAT.RSTSTAT;

if (reset_cause & PORST & SWD & PV )
{
    power_up_occured = true; //a normal power up occurred
    ...
}
if (reset_cause & WDT )
{
    watchdog_reset_occured = true; //a reset caused by watchdog
    ...
}
```

```
if (reset_cause & PARITY )
{
    parity_reset_occured = true; //reset caused by a parity error
    ...
}
...
```

4.11 Clear Reset Status

Reset status register needs to be cleared before a new reset cause can be effectively captured

- Clear wakeup-up status

Clear SCU_RSTSTAT.HIBWK with SCU_RSTCLR.HIBWK

- Clear reset status register

Clear SCU_RSTSTAT.RSTSTAT with SCU_RSTCLR.RSTSTAT

4.12 Restore Context Data from Retention Memory

Restore context specific data from the retention memory if a wake-up from Hibernate Mode has been positively detected in the previous steps. The use of the data is application specific.

- Issue a read command with SCU_RMACR.
- Read data from SCU_RMDATA register

Example pseudo-code:

```
//Read data from address 0x4 of the Retention Memory
//wait until RMACR register ready for a read command
do {
    } while ( SCU_GENERAL->MIRRSTS & SCU_GENERAL_MIRRSTS_RMX_Msk));

//write address 0x4

SCU_GENERAL->RMACR = (0x4 << SCU_GENERAL_RMACR_ADDR_Pos);

//wait until data available in the RMDATA register
do {
    } while ( SCU_GENERAL->MIRRSTS & SCU_GENERAL_MIRRSTS_RMX_Msk));

//read data for a write to retention memory in SCU_RMDATA register
Data = SCU_GENERAL -> RMDATA;
```

4.13 Execute Application Code

The application code starts.

The application code execution flow may depend on the wake-up source and context.

This step may also be specific to an Operating System.

Application Hints

5 Application Hints

5.1 Which Hibernate Mode to Choose

The optimal selection of the Hibernate Mode implementation is application specific and shall take in account requirements on current consumption, availability of on-chip and off-chip resources, cost etc. Some of the key points important from an application use case point of view shown in Table 1.

Table 3 Selection of the Hibernate Mode implementation

Features/hints	ECHM	ICHM
Power Consumption in Hibernate Mode	Ultra Low	Very Low
External Voltage Regulator	Required External Voltage Regulator capable of on/off control	Simple External Voltage Regulator
I/Os required	Minimum one I/O of Hibernate Domain	Possible without dedicated I/Os
Complexity of the circuit	pull-up resistors required	possible without pull-up resistors
Use cases	XMC4000 acting as the system power control master on the PCB Higher pin count packages Battery operated devices	XMC4000 acting as the system power control slave on the PCB Low pin count packages Power Supply Permanently available

5.2 Hibernate Domain Clock

The Hibernate domain clock is clocked with 32.768 MHz clock. The source of the clock may be selected:

- Internally generated clock source - Slow Internal Clock Source
- Externally generated clock source - OSC_SI oscillator with an external crystal
- Direct clock applied to the RTC clock pin

The choice of the clock shall be determined by the application specific requirements:

Table 4 Hibernate Domain Clock Source Selection

Trigger Source	Pins	Features/Hints
Internally generated clock source	n/a	<ul style="list-style-type: none"> • Low Bill of Material • Low power consumption • Most reliable RTC clock under all conditions • Moderate Real Time Clock accuracy
Externally generated clock source	RTC_XTAL0 & RTC_XTAL1	<ul style="list-style-type: none"> • Moderate Bill of Material • Very low power consumption • Very High Real Time Clock accuracy • Constrained PCB design
Direct clock applied to the RTC clock pin	RTC_XTAL0	<ul style="list-style-type: none"> • Higher Bill of Material • Easy PCB design • External oscillator supply required

5.3 Digital I/O Voltage Levels

In a typical Hibernate Mode application scenario the VBAT voltage level may be slightly lower than VDDP while in active mode due to presence of additional components e.g. a shottky diode between the VDDP and VBAT pin. Also, the VBAT level supplied to the chip may be even lower, and below any other supply sources on the PCB board which may potentially result in violation of the input/output voltage levels at the Hibernate Domain IOs (For details on voltage limits on I/Os please refer to Data Sheet). Therefore it is highly recommended to:

- Apply Open-Drain configuration with external pull-up to valid logic level high of the target signal for the output I/Os. The impedance of the pull-up shall be determined by the internal impedance of the input of the target circuit and the limits of the output I/O driver. The pull-up impedance needs to be dimensioned accordingly in order to avoid violation of the logic low level of the Hibernate Domain I/O limits. For details on the I/O limits please refer to Data Sheet.
- Drive the input I/Os with Open-Drain drivers and enable internal pull-up of the XMC4000 device to the VBAT voltage.

5.4 Analog I/O Voltage Levels

The voltage ranges for analog I/O wake-up trigger signals have a fixed maximum limit (For details please refer to Data Sheet), which is always below a valid VBAT voltage level. It is required to ensure that the output voltage level of a circuit connected to the analog wake-up trigger I/O according meets the specified limits. This can be easily done with a resistive voltage divider implemented on PCB, in front of the analog I/O of the XMC4000 device as depicted in Figure 1. The resistors R1 and R2 need to be dimensioned accordingly.

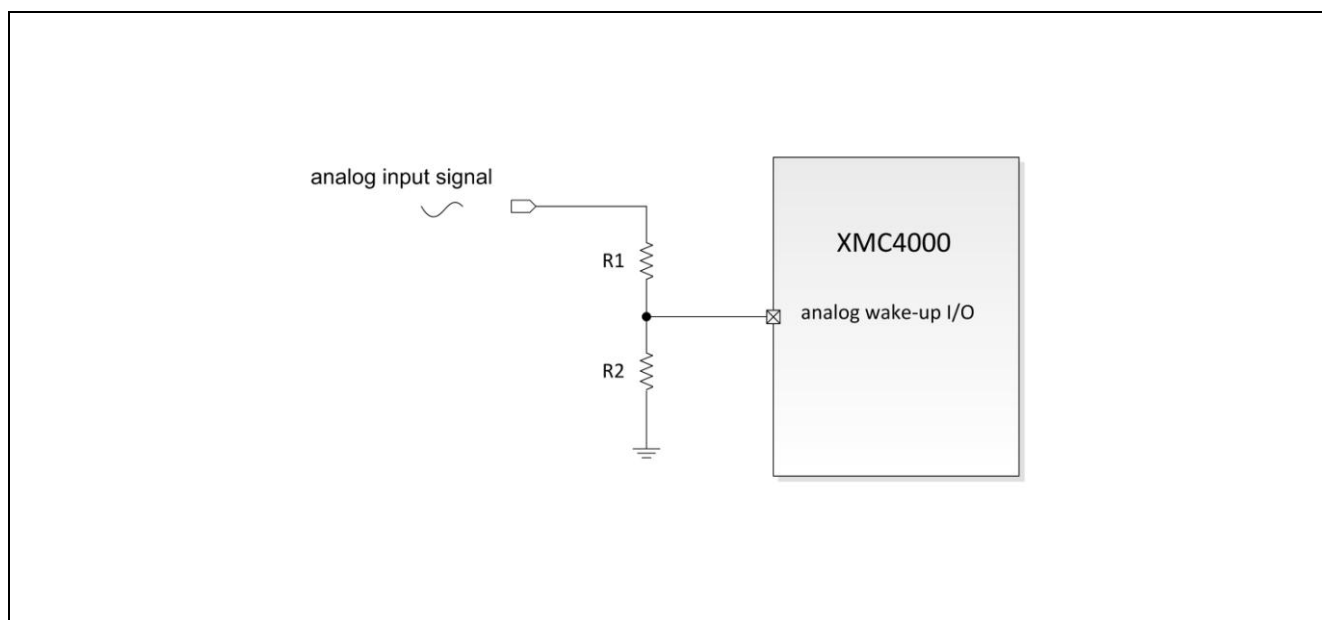


Figure 16 Analog signal input voltage divider

It is highly recommended to apply (possibly) high resistance R1 and R2 in to minimize the overall current in order to take maximum advantage of the power saving while in the Hibernate Mode.

5.5 Retention Memory

The internal Retention Memory in Hibernate Domain serves general purpose storage for context specific information to be used after a wake-up. This may include information e.g. on:

- reason for entering hibernate
- expected wake-up source relevant to the recent hibernate state
- action to be taken after a wakeup

The data stored in the Retention Memory has no direct effect on the hardware and it is entirely under the application software control.

5.6 Emergency Recovery from Hibernate Mode

It may happen that the system gets into a lock-up situation if a Hibernate Mode has been entered without a wake-up trigger selected. The XMC4000 device may permanently stay in the Hibernate State unless a corrective recovery action has been taken in order to bring it into operation. A few recovery hints are presented in the Table 3.

Table 5 Recovery Scenarios

Hibernate Mode	Action	Comments
Externally & Internally Controlled Hibernate Modes	Hibernate Domain Reset	Remove the V_{BAT} supply – not practicable e.g. if a coin battery soldered on the PCB. Lower the V_{BAT} level below reset threshold level – avoid a shortcut to ground, may damage the battery
Externally Controlled Hibernate Mode	Force generation of VDDP	Presence of VDDP supply will unconditionally force startup of the XMC4000 device, the Hibernate Domain will not get reset. This may be realized e.g. with a button allowing overwriting control signal of the External Voltage Regulator and forcing generation of VDDP, while V_{BAT} remains supplied.
Internally Controlled Hibernate Mode	Force removal of VDDP	Removal of VDDP supply will unconditionally remove Hibernate Mode. After reapplying VDDP supply the XMC4000 will start-up, the Hibernate Domain will not get reset. This may be realized e.g. by physically removing the module from the system, or, with a button allowing to overwriting control signal of the External Voltage Regulator and forcing removal of VDDP, while V_{BAT} remains supplied.

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